

**گروه فنی مهندسی جوش و برش مقدم** اعتماد از شما کیفیت و تخصص از ما

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مشهد خیام شمالی 63 خیابان پردیس 3 برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الكترونيكي دستگاه جوش
   تك فاز و 3 فاز
  - آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
    - آموزش تخصصی ابراز آلات شارژی



# RJH60F5DPQ-A0

600 V - 40 A - IGBT High Speed Power Switching

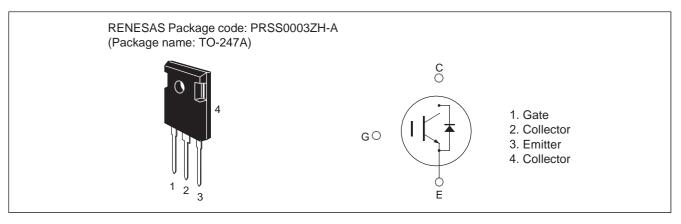
Datasheet

R07DS0326EJ0200 <u>Rev.2.00Jul 22, 2</u>011

#### Features

- Low collector to emitter saturation voltage V<sub>CE(sat)</sub> = 1.37 V typ. (I<sub>C</sub> = 40 A, V<sub>GE</sub> = 15 V, Ta = 25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching  $t_r = 85$  ns typ. (at  $I_C = 30$  A,  $V_{CE} = 400$  V,  $V_{GE} = 15$  V,  $Rg = 5 \Omega$ ,  $Ta = 25^{\circ}C$ , inductive load)

### Outline



## **Absolute Maximum Ratings**

				(Tc = 25°C)
ltem		Symbol	Ratings	Unit
Collector to emitter voltage		V <sub>CES</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25 °C	Ι <sub>C</sub>	80	А
	Tc = 100 °C	lc	40	А
Collector peak current		ic(peak) Note1	160	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) <sup>Note2</sup>	100	А
Collector dissipation		Pc	260.4	W
Junction to case thermal impedance (IGBT)		өј-с	0.48	°C/W
Junction to case thermal impedance (Diode)		θj-cd	2.0	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. PW  $\leq$  5  $\mu$ s, duty cycle  $\leq$  1%



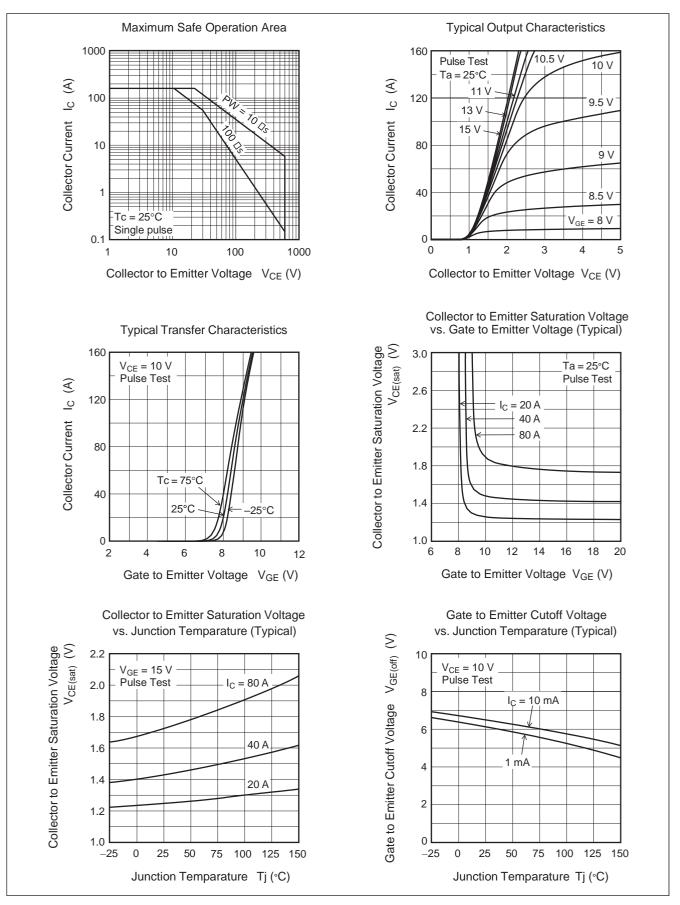
## **Electrical Characteristics**

						(Tj = 25°C)
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub>	_	_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I <sub>GES</sub>	_		±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4	_	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.37	1.8	V	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V}^{Note3}$
	V <sub>CE(sat)</sub>	_	1.7		V	$I_{C} = 80 \text{ A}, V_{GE} = 15 \text{ V}^{Note3}$
Input capacitance	Cies	_	2780		pF	V <sub>CE</sub> = 25 V
Output capacitance	Coes	_	122		pF	V <sub>GE</sub> = 0 V f = 1 MHz
Reverse transfer capacitance	Cres		43		pF	
Switching time	t <sub>d(on)</sub>		53		ns	Ic = 30 A,
	tr		145		ns	$V_{CE} = 400 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$
	t <sub>d(off)</sub>		105		ns	$Rg = 5 \Omega^{Note3},$ Inductive load
	t <sub>f</sub>		85		ns	
C-E diode forward voltage	V <sub>ECF1</sub>		1.2	2.1	V	I <sub>F</sub> = 20 A <sup>Note3</sup>
	V <sub>ECF2</sub>		1.5		V	I <sub>F</sub> = 40 A <sup>Note3</sup>
C-E diode reverse recovery time	t <sub>rr</sub>		90		ns	I <sub>F</sub> = 20 A
						di⊧/dt = 100 A/µs

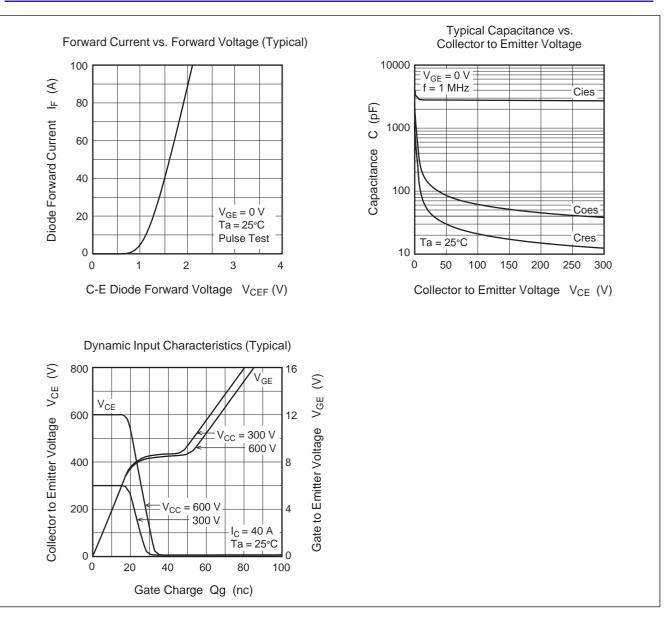
Notes: 3. Pulse test



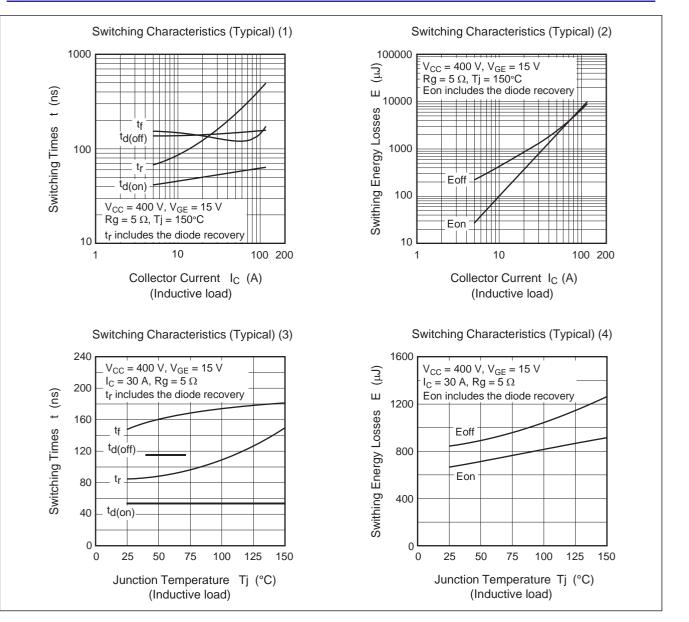
#### **Main Characteristics**



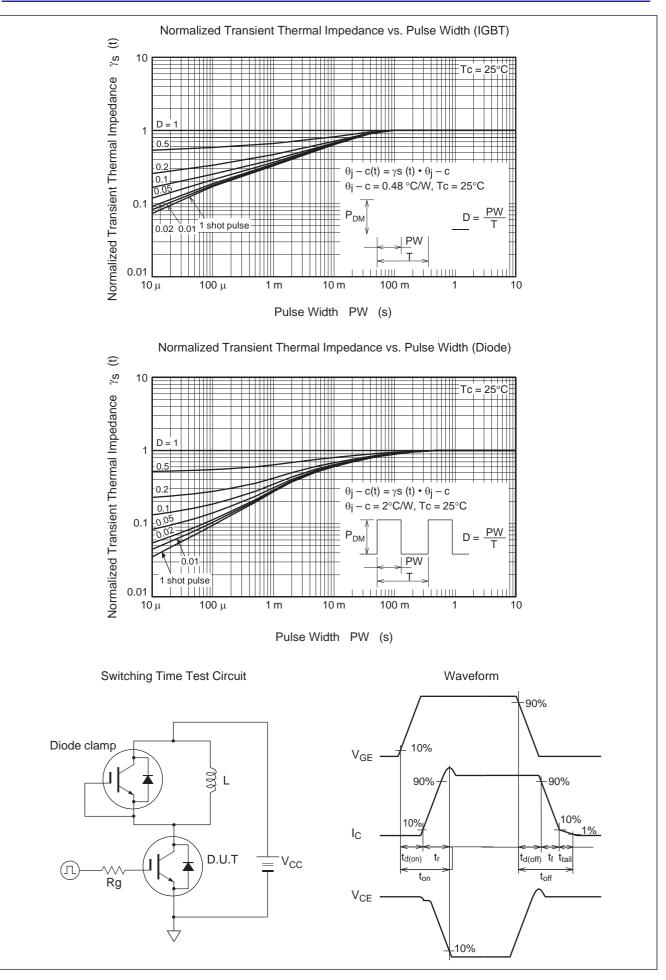






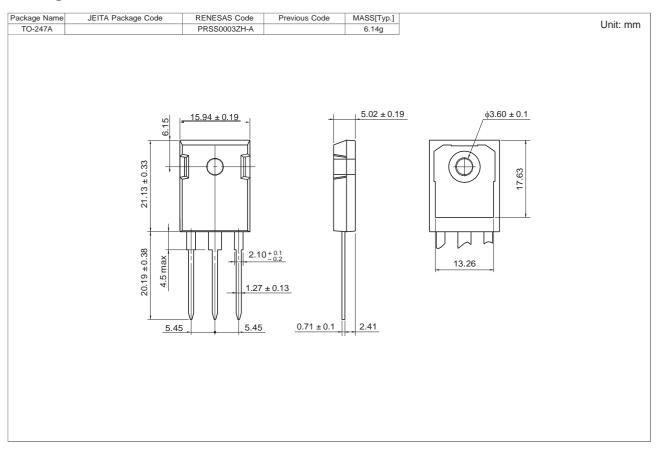








#### **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container	
RJH60F5DPQ-A0-T0	240 pcs	Box (Tube)	



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